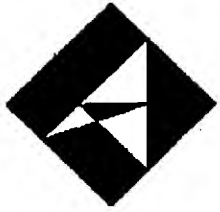


A T M I**7 Commerce Drive, Danbury, CT 06810 203.794.1100 203.797.2544**
web.atmi.com info@atmi.com**facsimile transmittance****RECEIVED
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To: Examiner Porfirio Nazario Gonzalez, **Fax:** 703.872.9306
From: Mag Chappuis **Date:** August 26 2004
E-mail: Mchappuis@atmi.com **Pages:** 32
Re: Response to February 26, 2004 Office Action in U.S. Application Serial No. 09/954,831 **cc:**

OFFICIAL COMMUNICATION

AMENDMENT RESPONDING TO FEBRUARY 26, 2004 OFFICE ACTION IN U.S. PATENT APPLICATION NO. 09/954,831 AND PETITION FOR EXTENSION OF TIME UNDER 37 C.F.R. § 1.136

Dear Examiner Nazario Gonzalez:

Please find enclosed a Response to the February 26, 2004 Office Action in US Patent Application No. 09/954,831, for Source Reagent Compositions for CVD Formation of Gate Dielectric Thin Films Using Amide Precursors and Method of Using Same, including:

Response - 21 sheets
Appendix A - 10 sheets
Facsimile Transmittal - 1 sheet

Please call 203-739-1435 if there are any problems with this transmittal.

Maggie Chappuis

ATMI, Inc.
7 Commerce Drive
Danbury, CT 06810
203-794-1100 (telephone)
203-797-2544 (facsimile)
ATMI Docket: ATM-510 CIP

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